

Notice of References Cited	Application/Control No. 10/541,815		Applicant(s)/Patent Under Reexamination GERLT ET AL.	
	Examiner MATTHEW W. SUCH		Art Unit 2891	Page 1 of 1

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*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
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*	B	US-6,958,270	10-2005	Misra et al.	438/257
*	C	US-4,721,601	01-1988	Wrighton et al.	422/82.03
*	D	US-4,717,673	01-1988	Wrighton et al.	436/68
*	E	US-4,945,257	07-1990	Marrocco, III, Matthew L.	338/38
*	F	US-6,323,309	11-2001	Swager et al.	528/380
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	M	US-			

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NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)			
*	U	Roth, K.M, et al. "Characterization of Charge Storage in Redox-Active Self-Assembled Monolayers." LANGMUIR, Vol. 18 (2002): pp. 4030-4040.			
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*	W	Ruzyllo, J. SEMICONDUCTOR GLOSSARY: AN INTRODUCTION TO SEMICONDUCTOR TECHNOLOGY. Prosto Multimedia Publishing: State College (2004): pp. 103.			
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.